Marubeni

Data Sheet

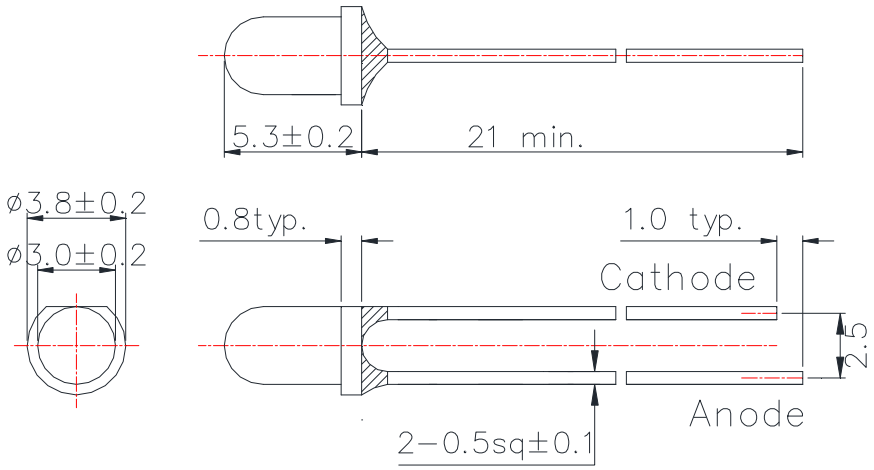
2021.06

PRELIMINARY

L1050GD-33

Infrared LED Lamp

Outline and Internal Circuit



(Unit : mm)

Features

· Chip Material : GaAs

· Chip Dimension : 350um * 350um

· Number of Chips : 1pce

· Peak Wavelength : 1050nm typ.

· Package Type : ·3mm clear molding

· Lead Frame : Soldered (Lead Free)

· Lens : Epoxy Resin

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Absolute Maximum Ratings (Tc=25°C)

Item	Symbol	Ratings	Unit
Power Dissipation	PD	160	mW
Forward Current	IF	100	mA
Pulse Forward Current	IFP	1000	mA
Reverse Voltage	VR	5	V
Thermal Resistance	Rthjs	200	K/W
Junction Temperature	Tj	120	°C
Operating Temperature	Topr	-40 ~ +100	°C
Storage Temperature	Tstg	-40 ~ +100	°C
Soldering Temperature	TSOL	265	°C

‡Pulse Forward Current condition : Duty 1% and Pulse Width=10us.

‡Soldering condition : Soldering condition must be completed with 3 seconds at 265°C.

Optical and Electrical Characteristics (Tc=25°C)

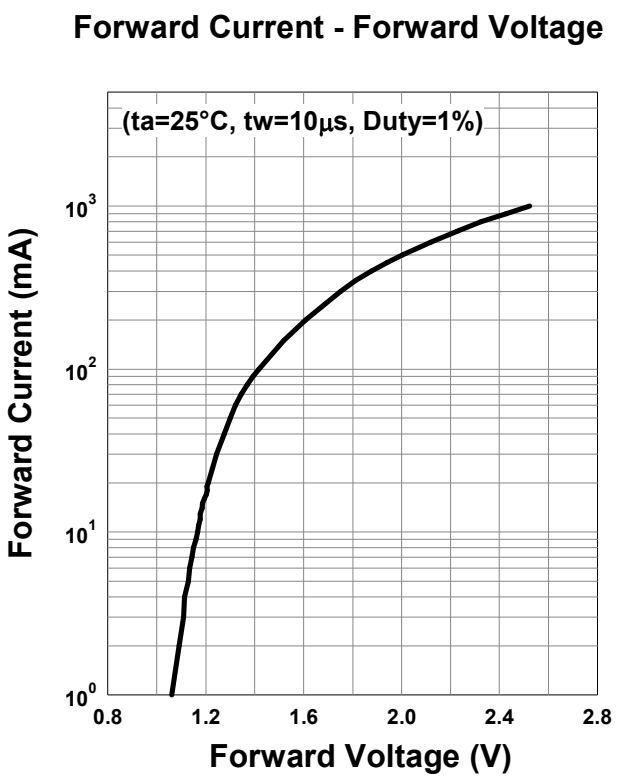
(*: 100% testing, **: reference value)

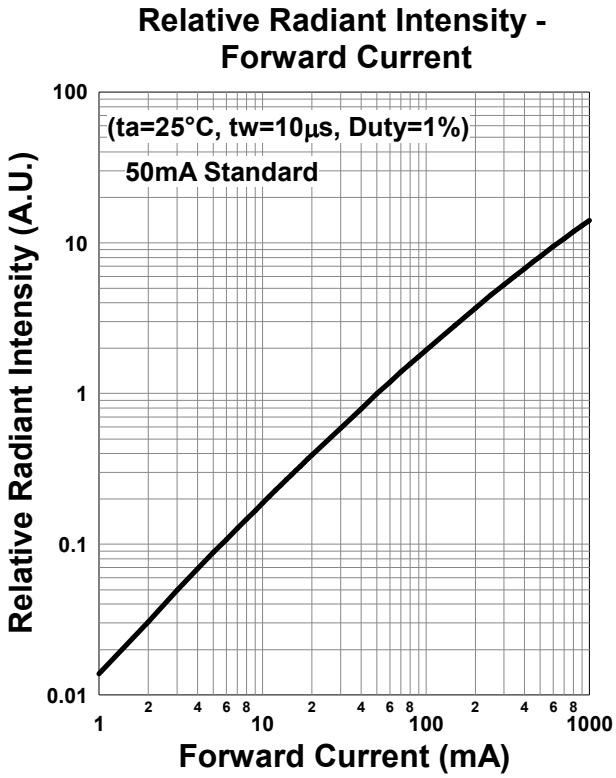
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Forward Voltage	VF		1.3	(1.6)	V	IF=50mA*
	VFP		2.5			IFP=1A**
Reverse Current	IR			10	uA	VR=5V*
Total Radiated Power	PO	21	30		mW	IF=50mA**
			420			IFP=1A**
Radiant Intensity	IE		95		mW/sr	IF=50mA**
			1300			IFP=1A**
Peak Wavelength	λp	1000		1100	nm	IF=50mA**
Half Width	Δλ		50		nm	IF=50mA**
Viewing Half Angle	θ1/2		±19		deg.	IF=50mA**
Rise Time	tr		10		ns	IF=50mA**
Fall Time	tf		10		ns	IF=50mA**

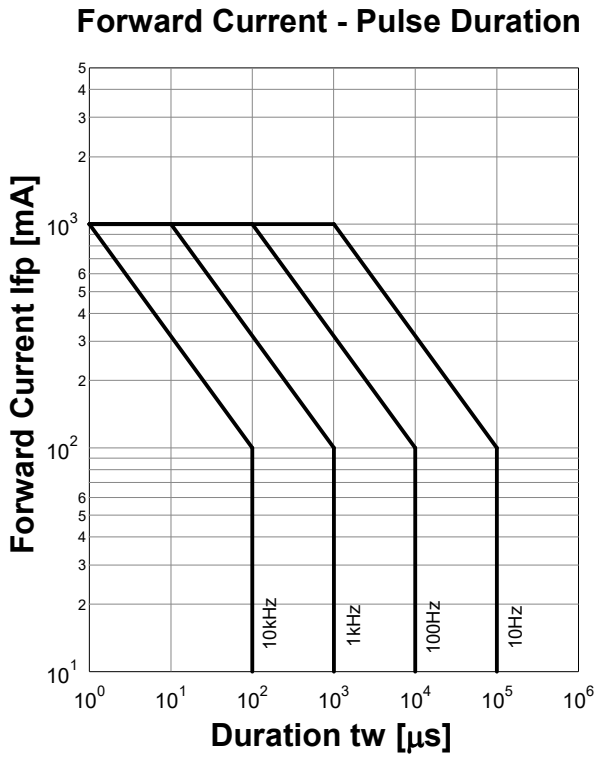
‡ Radiated Power is measured by G8370-85.

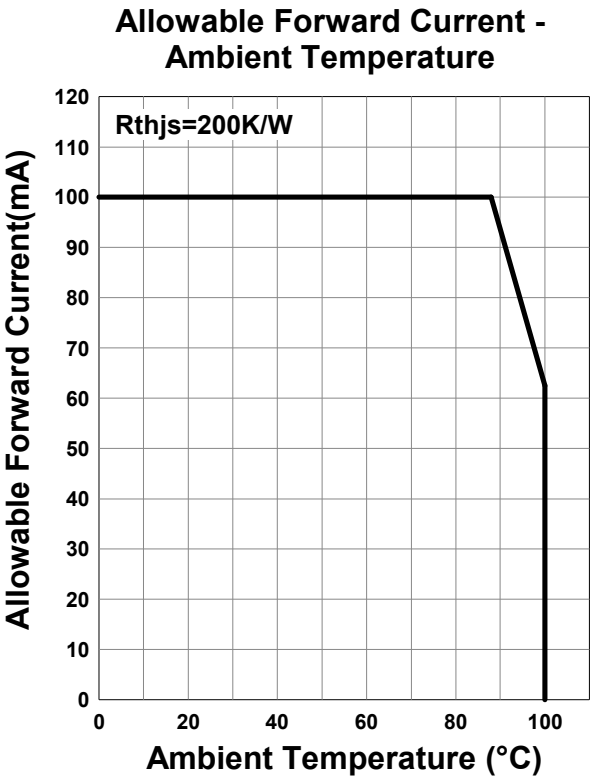
‡ Radiant Intensity is measured by Ando Optical Multi Meter AQ2140 & AQ2742.

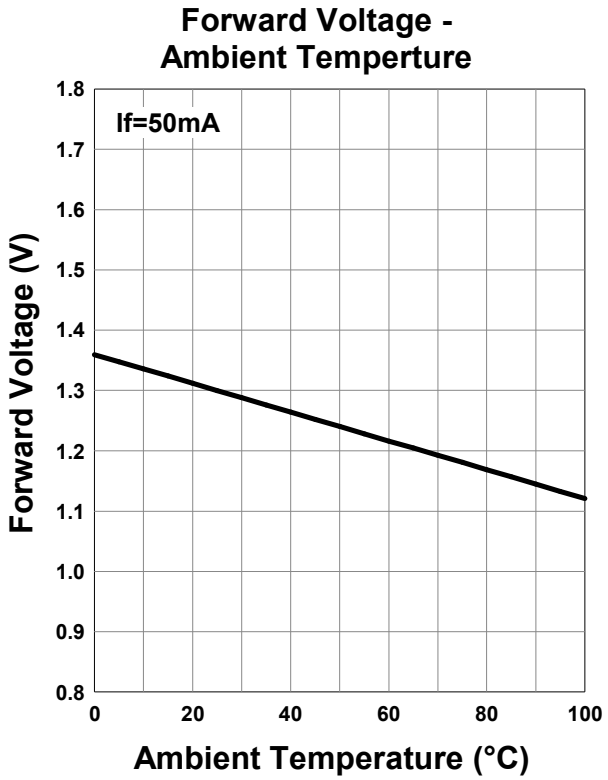
Typical Characteristic Curves

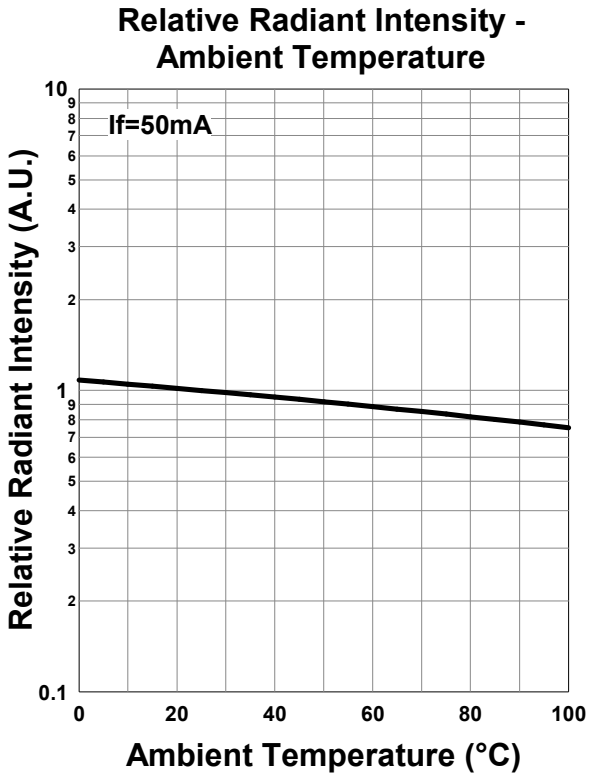


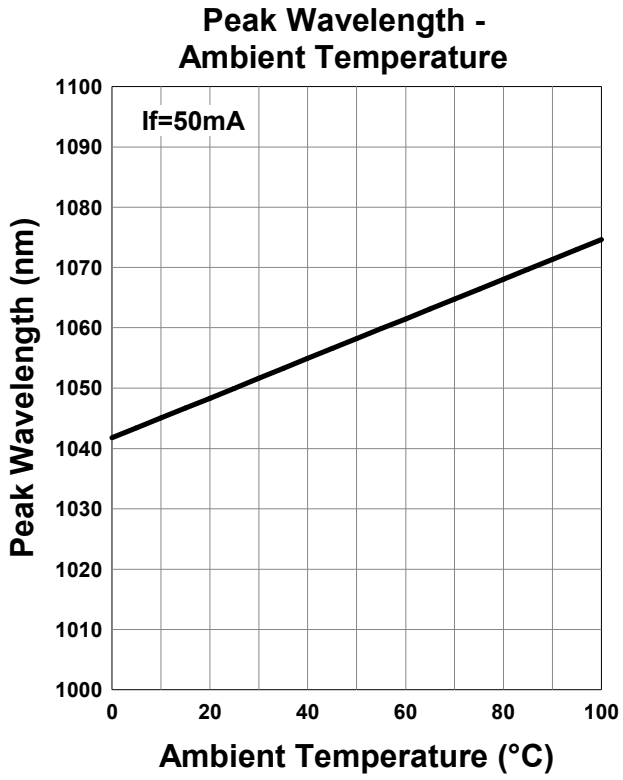







Forward Voltage -
Ambient Temperture
If=50mA
Forward Voltage (V)
1.8
1.7
1.6
1.5
1.4
1.3
1.2
1.1
1.0
0.9
0.8
0
20
40
60
80
100
Ambient Temperature (°C)


Relative Radiant Intensity -
Ambient Temperature
If=50mA
Relative Radiant Intensity (A.U.)
10
9
8
7
6
5
4
3
2
1
0.1
0
20
40
60
80
100
Ambient Temperature (°C)


Peak Wavelength -
Ambient Temperature
If=50mA
Peak Wavelength (nm)
1100
1090
1080
1070
1060
1050
1040
1030
1020
1010
1000
0
20
40
60
80
100
Ambient Temperature (°C)

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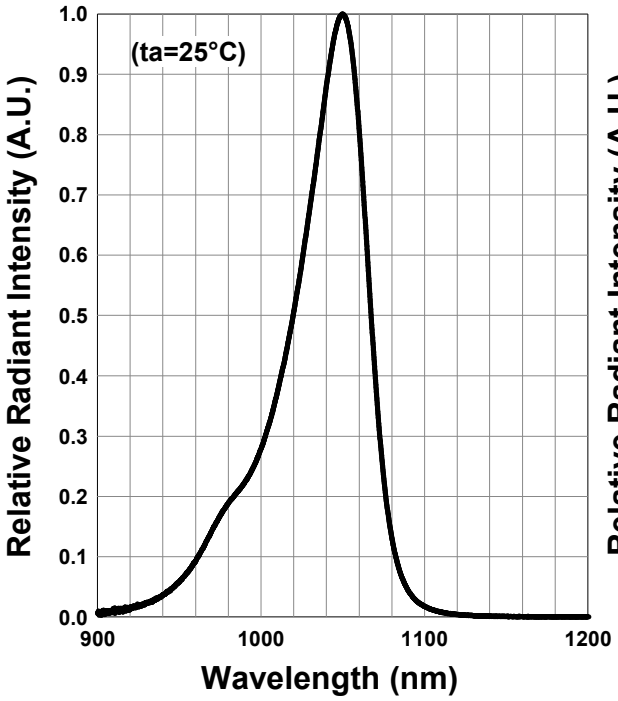
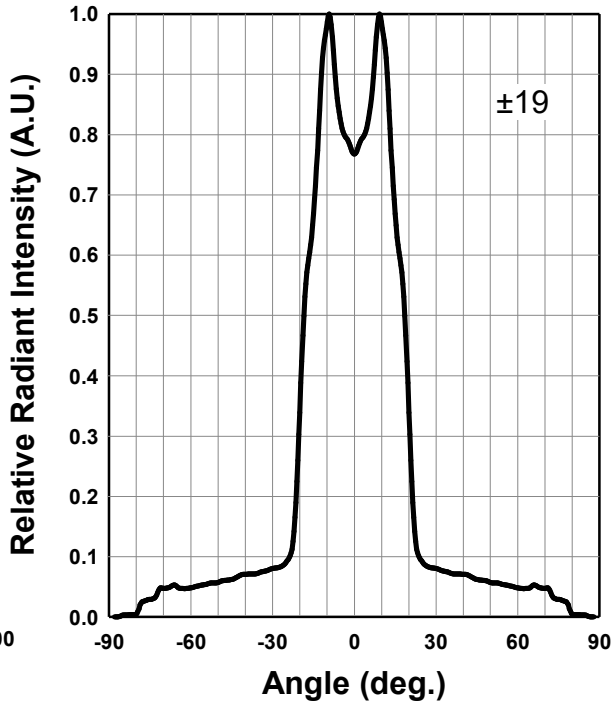
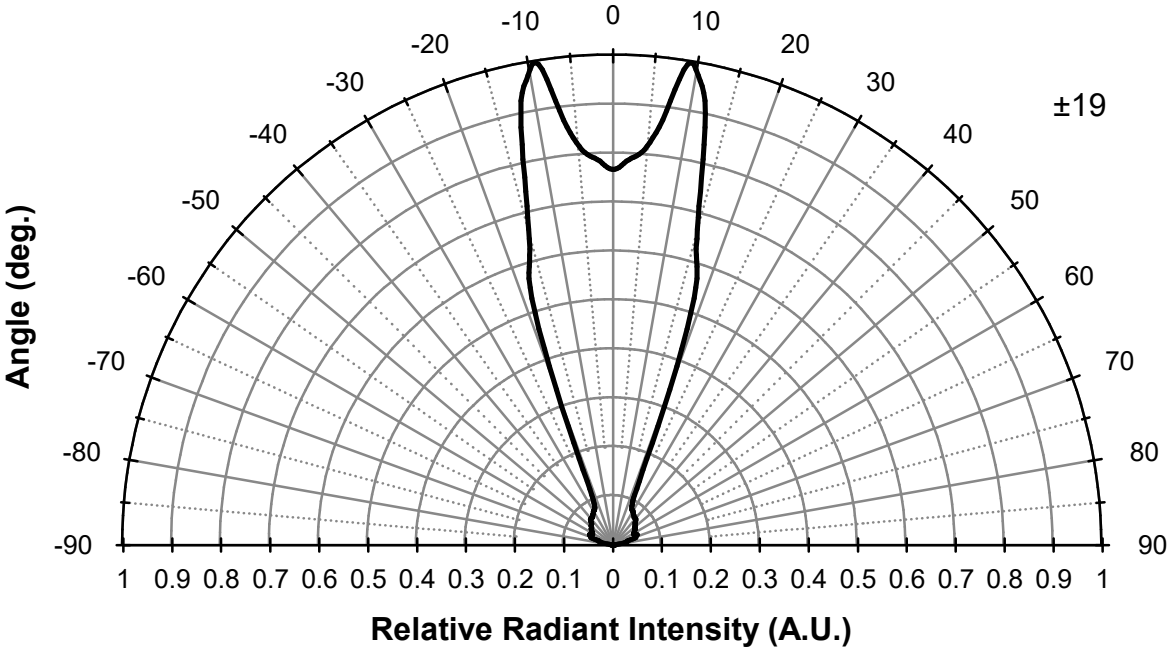
Relative Spectral Emission



Radiation Characteristics



Radiation Characteristics



Disclaimer

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Product data and parameters in this catalog are typical values based on reasonably up-to-date measurements. Product data and parameters may vary by user application and over time.

Products shown in this catalog are intended to be used for general electronic equipment. Products are not guaranteed for applications where product malfunction or failure may cause personal injury or death, including but not limited to life-supporting / saving devices, medical devices, safety devices, airplanes, aerospace equipment, automobiles, traffic control systems, and nuclear reactor control systems.

Technical Support Information

The product is manufactured by USHIO Inc. and the spec information is also from USHIO Inc.